

#### **Features and Benefits**

- Single supply operation
- Very small outline package
- Low R<sub>DS(ON)</sub> outputs
- Sleep function
- Internal UVLO
- Crossover current protection
- Thermal shutdown protection

### Packages:



Package LB, 16-pin SOIC with internally fused pins

Not to scale

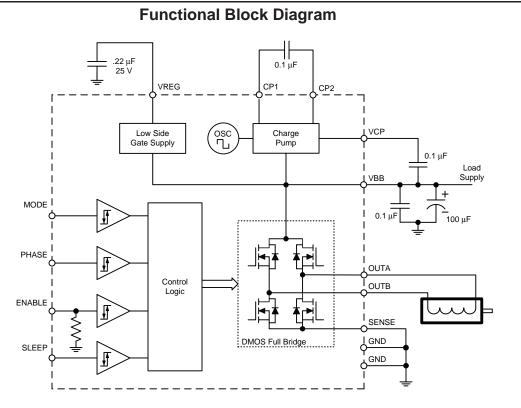
#### Description

Designed for PWM (pulse width modulated) control of DC motors, the A3949 is capable of peak output currents to  $\pm 2.8$  A and operating voltages to 36 V.

PHASE and ENABLE input terminals are provided for use in controlling the speed and direction of a DC motor with externally applied PWM control signals. Internal synchronous rectification control circuitry is provided to reduce power dissipation during PWM operation.

Internal circuit protection includes thermal shutdown with hysteresis, undervoltage monitoring of  $V_{\rm BB}$  and  $V_{\rm CP},$  and crossover current protection.

The A3949 is supplied in a power package, a 16-pin plastic SOIC with a copper batwing tab (part number suffix LB). The packages are lead (Pb) free, with 100% matte tin leadframes.



#### 29319.47i

#### **Selection Guide**

Part Number	Package	Packing
A3949SLBTR-T	16-pin, SOIC	1000 per reel

#### **Absolute Maximum Ratings**

Characteristic	Symbol	Notes	Rating	Units
Lood Supply Voltage	V <sub>BB</sub>		36	V
Load Supply Voltage		Peak < 2 µs	38	V
Logic Input Voltage	V <sub>IN</sub>		–0.3 to 7	V
Sense Voltage	V		0.5	V
Output Current, Repetitive	I <sub>OUT</sub>	Output current rating may be limited by duty cycle, ambient temperature, and heat sinking. Under any set of conditions, DO NOT exceed the specified $I_{OUT}$ or $T_{J}$ .	±2.8	A
Operating Ambient Temperature	T <sub>A</sub>	Range S	–20 to 85	°C
Maximum Junction Temperature	T <sub>J</sub> (max)		150	°C
Storage Temperature	T <sub>stg</sub>		–55 to 150	°C

#### Package Thermal Characteristics\*

Characteristic	Symbol	Note	Rating	Units	
Package Thermal Resistance	R <sub>eja</sub>	Measured on 2-layer PCB with 2 in? 2-oz. copper each side	52	°C/W	
*Additional information is available on the Allegro website					

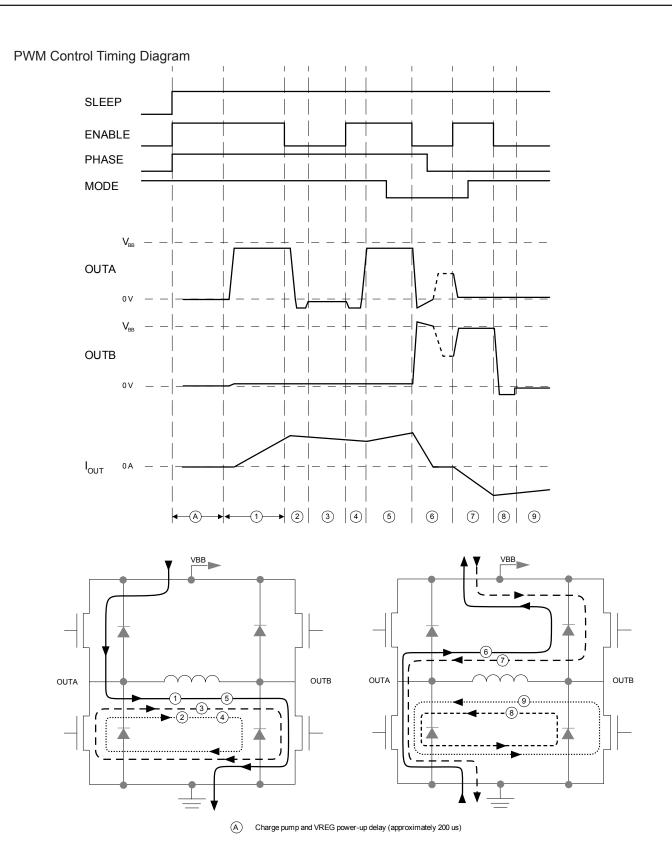
\*Additional information is available on the Allegro website.



### **ELECTRICAL CHARACTERISTICS** at $T_A = 25^{\circ}$ C, $V_{BB} = 8$ V to 36 V (unless otherwise noted)

Characteristics	Symbol	Test Conditions	Min.	Тур.	Max.	Units
	R <sub>dson</sub>	Source driver, $I_{OUT} = -2.8 \text{ A}, T_{J} = 25^{\circ}\text{C}$	_	.4	.48	Ω
Output-On Resistance		Source driver, $I_{OUT} = -2.8 \text{ A}, T_{J} = 125^{\circ}\text{C}$	_	.68	_	Ω
		Sink driver, $I_{OUT} = 2.8 \text{ A}, T_J = 25^{\circ}\text{C}$	_	.3	.43	Ω
		Sink driver, $I_{OUT} = -2.8 \text{ A}, T_J = 125^{\circ}\text{C}$	_	.576	_	Ω
Dedu Diede Ferrural Malterre		Source diode, $I_F = -2.8 \text{ A}$	_	1.1	1.3	V
Body Diode Forward Voltage	$V_{F}$	Sink diode, I <sub>F</sub> = 2.8 A	_	1	1.3	V
		f <sub>PWM</sub> < 50 kHz	_	6	8.5	mA
Motor Supply Current	I <sub>BB</sub>	Charge pump turned on; outputs disabled	_	3	4.5	mA
		Sleep mode	_	-	10	μA
Logic Input Voltage	V <sub>IN(1)</sub>		2.0	-	-	V
PHASE, ENABLE, MODE	V <sub>IN(0)</sub>		_	-	0.8	V
Logic Input Voltage	V <sub>IN(1)</sub>		2.7	-	_	V
SLEEP	V <sub>IN(0)</sub>		_	-	0.8	V
Logic Input Current	I <sub>IN(1)</sub>	V <sub>IN</sub> = 2.0 V	_	< 1.0	20	μA
PHASE, MODE pins	I <sub>IN(0)</sub>	V <sub>IN</sub> = 0.8 V	_	< -2.0	-20	μA
Logic Input Current	I <sub>IN(1)</sub>	V <sub>IN</sub> = 2.0 V	_	40	100	μA
ENABLE pin	I <sub>IN(0)</sub>	V <sub>IN</sub> = 0.8 V	_	16	40	μA
Logic Input Current	I <sub>IN(1)</sub>	V <sub>IN</sub> = 2.7 V	_	27	50	μA
SLEEP pin	I <sub>IN(0)</sub>	V <sub>IN</sub> = 0.8 V	_	< 1	10	μA
Deve e se tiere Deles Tiere e	t <sub>pd</sub>	From PWM change to source or sink turn on	_	600	_	ns
Propagation Delay Times		From PWM change to source or sink turn off	_	100	_	ns
Crossover Delay	t <sub>cod</sub>		_	500	_	ns
Protection Circuitry						
UVLO Enable Threshold		VBB rising	_	6		V
UVLO Hysteresis			_	250	_	mV
Thermal Shutdown Temp.	TJ		_	170	-	°C
Thermal Shutdown Hysteresis	al Shutdown Hysteresis ΔT		_	15	_	°C







Allegro MicroSystems, LLC 115 Northeast Cutoff Worcester, Massachusetts 01615-0036 U.S.A. 1.508.853.5000; www.allegromicro.com

### **Functional Description**

**VREG.** This supply voltage is used to operate the sinkside DMOS outputs. VREG is internally monitored and in the case of a fault condition, the outputs of the device are disabled. The VREG pin should be decoupled with a  $0.22 \ \mu F$ capacitor to ground.

**Charge Pump.** The charge pump is used to generate a supply above VBB to drive the source-side DMOS gates. A 0.1 uF ceramic monolithic capacitor should be connected between CP1 and CP2 for pumping purposes. A 0.1 uF ceramic monolithic capacitor should be connected between VCP and VBB to act as a reservoir to run the high side DMOS devices. The VCP voltage is internally monitored, and in the case of a fault condition, the outputs of the device are disabled.

**Shutdown.** In the event of a fault due to excessive junction temperature, or low voltage on VCP or VREG, the outputs of the device are disabled until the fault condition is removed. At power-up, the UVLO circuit disables the drivers.

**Sleep Mode.** Control input SLEEP is used to minimize power consumption when the A3949 is not in use. This disables much of the internal circuitry, including the low-side gate supply and the charge pump. A logic low on this pin puts the device into Sleep mode. A logic high allows normal operation. After coming out of Sleep mode, the user should wait 1 ms before applying PWM signals, to allow the charge pump to stabilize.

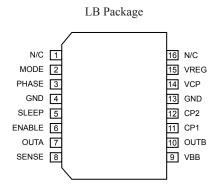
**Braking.** The braking function is implemented by driving the device in slow decay mode via the MODE pin, and applying an enable chop command. Because it is possible to drive current in both directions through the DMOS switches, this configuration effectively shorts out the motor-generated BEMF, as long as the enable chop mode is asserted on the ENABLE pin. The maximum current can be approximated by  $V_{BEMF}/R_L$ . Care should be taken to insure that the maximum ratings of the device are not exceeded in worse case braking situations of high speed and high inertial loads.

PHASE	ENABLE	MODE	SLEEP	OUTA	OUTB	Function
1	1	Х	1	Н	L	Forward
0	1	Х	1	L	Н	Reverse
X	0	1	1	L	L	Brake (slow decay)
1	0	0	1	L	н	Fast decay SR*
0	0	0	1	Н	L	Fast decay SR*
Х	Х	Х	0	Hi-Z	Hi-Z	Sleep mode

Control Logic Table

\* To prevent reversal of current during fast decay SR (synchronous rectification), the outputs go to the high impedance state as the current approaches zero.



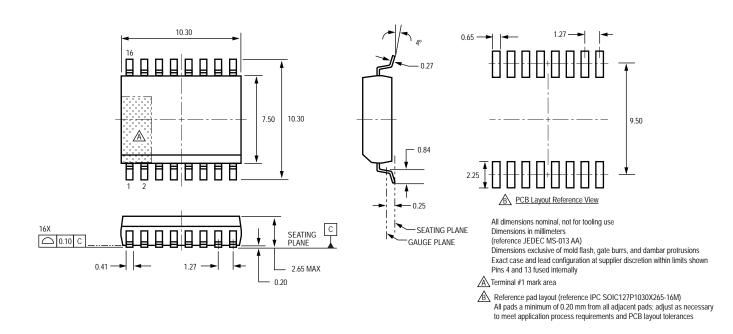


Name	Description	Number
N/C	Not used	1
MODE	Logic input	2
PHASE	Logic input for direction control	3
GND	Ground	4*
SLEEP	Logic input	5
ENABLE	Logic input	6
OUTA	Output A for full bridge	7
SENSE	Power return	8
VBB	Load supply voltage	9
OUTB	Output B for full bridge	10
CP1	Charge pump capacitor	11
CP2	Charge pump capacitor	12
GND	Ground	13*
VCP	Reservoir capacitor	14
VREG	Low side gate supply decoupler	15
N/C	Not used	16

\*These pins are internally connected.



LB 16-Pin SOICW



Copyright ©2003-2013, Allegro MicroSystems, LLC

Allegro MicroSystems, LLC reserves the right to make, from time to time, such departures from the detail specifications as may be required to permit improvements in the performance, reliability, or manufacturability of its products. Before placing an order, the user is cautioned to verify that the information being relied upon is current.

Allegro's products are not to be used in life support devices or systems, if a failure of an Allegro product can reasonably be expected to cause the failure of that life support device or system, or to affect the safety or effectiveness of that device or system.

The information included herein is believed to be accurate and reliable. However, Allegro MicroSystems, LLC assumes no responsibility for its use; nor for any infringement of patents or other rights of third parties which may result from its use.

For the latest version of this document, visit our website: www.allegromicro.com

